

BTA04 T/D/S/A BTB04 T/D/S/A

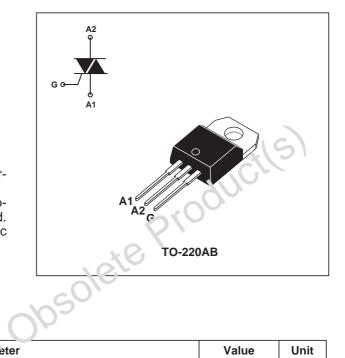
SENSITIVE GATE TRIACS

FEATURES

- Very low I_{GT} = 10mA max
- Low $I_H = 15 \text{mA max}$
- BTA Family: Insulating voltage = 2500V_(RMS) (UL recognized: E81734)

DESCRIPTION

The BTA/BTB04 T/D/S/A triac family are high performance glass passivated PNPN devices. These parts are suitables for general purpose applications where gate high sensitivity is required. Application on 4Q such as phase control and static switching.



ABSOLUTE RATINGS	(limiting values)
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Symbol	Parameter			Value	Unit
I _{T(RMS)}	RMS on-state current (360° cor auction angle)	BTA	Tc = 90°C	4	Α
		BTB	Tc = 95°C		
I _{TSM}	Non repetitive surge peak or i-state current		tp = 8.3ms	42	А
	$(Tj initial = 25^{\circ}C)$			40	
l ² t	l ² t value		tp = 10ms	8	A ² s
dl/dt Critical cie of rise of on-state current Gate supply: I _G = 50mA dl _G /dt = 0.1A/µs		Repetitive F = 50Hz	10	A/µs	
Non rep			Non repetitive	50	
Tstg T,	Storage and operating junction temperature range			-40 to +150 -40 to +110	°C
- TI	Maximum lead soldering temperature during 10s a	it 4.5mm fi	rom case	260	°C

Symbol Parameter		BTA / BTB04-				
Symbol	Parameter	400 T/D/S/A	600 T/D/S/A	700 T/D/S/A	Unit	
V _{drm} V _{rrm}	Repetitive peak off-state voltage Tj = 110°C	400	600	700	V	

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THERMAL RESISTANCE

Symbol	Parameter		Value	Unit
Rth (j-a)	Junction to ambient		60	°C/W
Rth (j-c) DC	Junction to case for DC	BTA	4.4	°C/W
		BTB	3.2	
Rth (j-c) AC	Junction to case for 360° conduction angle (F = 50Hz)	BTA	3.3	°C/W
		BTB	2.4	

GATE CHARACTERISTICS (maximum values)

 $P_{G(AV)} = 1W$ $P_{GM} = 40W$ (tp = 20µs) $I_{GM} = 4A$ (tp = 20µs) $V_{GM} = 16V$ (tp = 20µs)

ELECTRICAL CHARACTERISTICS

Cumhal	DI Test conditions Quadrant		Quedrant		BTA / BTB04				L Inci 4
Symbol				т	D	S	A	Unit	
I _{GT}	$V_D = 12V (DC)$ $R_L = 33\Omega$	Tj = 25°C	- -	MAX.	5	5	10	10	mA
			IV	MAX.	5	10	10	25	
V _{GT}	$V_{D} = 12V (DC) R_{L} = 33\Omega$	Tj = 25°C	I - II - III - IV	MAX.		07	.5		V
V _{GD}	$V_D = V_{DRM}$ $R_L = 3.3 k\Omega$	Tj =110°C	I - II - III - IV	MIN.	X	0	.2		V
tgt	$\label{eq:VD} \begin{array}{l} V_D = V_{DRM} I_G = 40 mA \\ dI_G/dt = 0.5 A/\mu s \end{array}$	Tj = 25°C	- - - V	TYP.	0		2		μs
١L	$I_{G} = 1.2I_{GT}$	Tj = 25°C	I - III - IV	TYP.	10	10	20	20	mA
			ll-		20	20	40	40	
I _H *	I _T = 100mA Gate open	Tj = 25°C		MAX.	15	15	25	25	mA
V _{TM} *	$I_{TM} = 5.5A$ tp = 380µs	Tj = 25°C		MAX.	1.65			V	
I _{DRM}	V _{DRM} rated	Tj = 25°C		MAX.		0.	01		mA
I _{RRM}	V _{RRM} rated	Tj = 110°C		MAX.		0.	75		
dV/dt *	Linear slope up to	Tj = 110°C		TYP.	10	10	-	-	V/µs
	$V_D = 67\% V_{DRM}$ gate open			MIN.	-	-	10	10	
(dl/dt)c*	(dl/dt)c = 1.8A/ms	Tj = 110°C		TYP.	1	1	5	5	V/µs

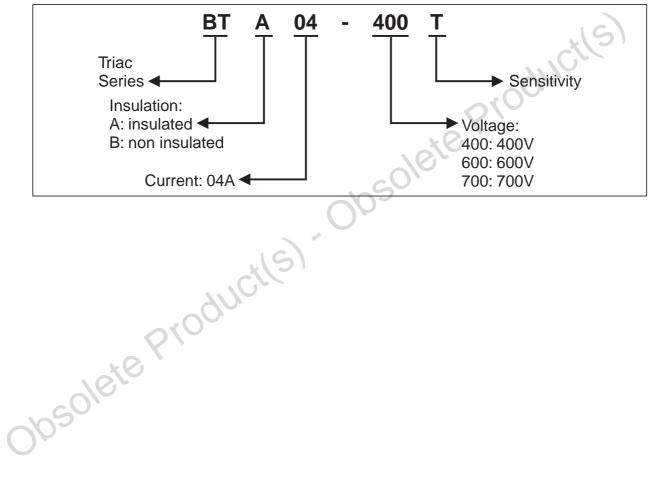
57

* For either polarity of electrode A2 voltage with reference to electrode A1

PRODUCT INFORMATION

Dealassa	I _{T(RMS)}	V _{DRM} / V _{RRM}	Sensitivity Specification				
Package –	Α	v	т	D	S	А	
BTA	4	400	Х			Х	
(Insulated)		600	Х	Х			
		700	Х		Х		
BTB		400	Х	Х			
(Uninsulated)		600	х		Х		

ORDERING INFORMATION



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Fig. 1: Maximum RMS power dissipation versus RMS on-state current (F = 50Hz).(Curves are cut off by (dl/dt)c limitation)

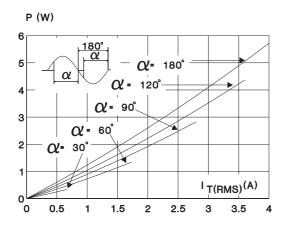


Fig. 3: Correlation between maximum RMS power dissipation and maximum allowable temperature (Tamb and Tcase) for different thermal resistances heatsink + contact (BTB).

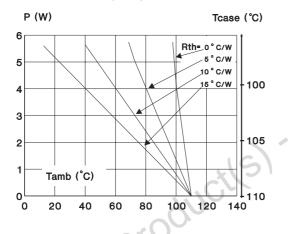


Fig. 5: Relative variation of thermal impedance versus pulse duration.

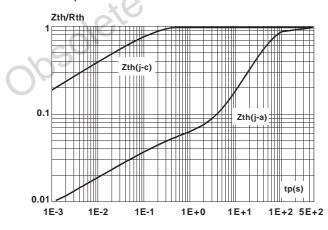


Fig. 2: Correlation between maximum RMS power dissipation and maximum allowable temperature (Tamb and Tcase) for different thermal resistances heatsink + contact (BTA).

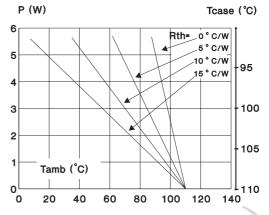


Fig. 4: RMS on-state current versus case temperature.

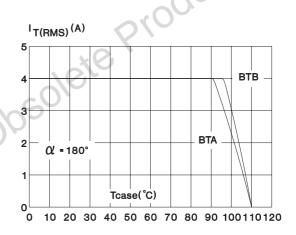
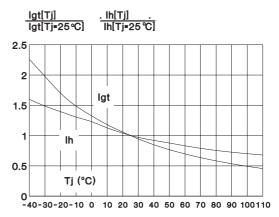


Fig. 6: Relative variation of gate trigger current and holding current versus junction temperature.



4/6

5

I TSM

5

t (ms)

10

Fig. 7: Non repetitive surge peak on-state current versus number of cycles.

Fig. 8: Non repetitive surge peak on-state current for a sinusoidal pulse with width: $t \le 10$ ms, and corresponding value of l²t.

Tj initial = 25°C

 $I_{TSM}(A)$. $I^{2}t (A^{2}s)$

l²t ¥

2

200

100

10

1

1

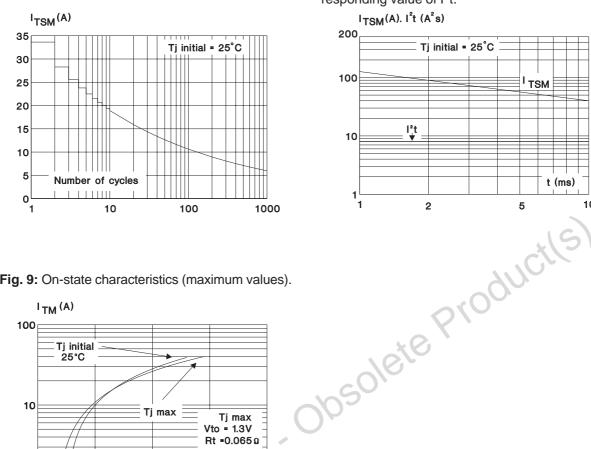
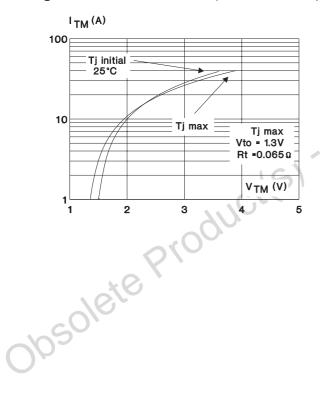


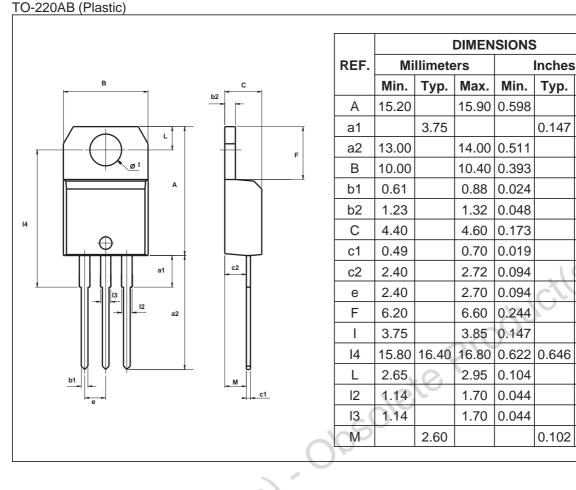
Fig. 9: On-state characteristics (maximum values).





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PACKAGE MECHANICAL DATA



OTHER INFORMATION

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BTA/BTB04-xxxy	BTA/BTB04-xxxy	TO-220AB	2.3 g	250	Bulk

Epoxy meets UL94,V0

- Cooling method: C
- Recommended torque value: 0.8 m.N.
- Maximum torque value: 1 m.N.

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Max.

0.625

0.551

0.409

0.034

0.051

0.181

0.027

0.107

0.106

0.259

0.151

0.661

0.116

0.066

0.066

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